

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:

Hatakeyama et al.

Group Art Unit: TBA

Serial No.:

TBA

Examiner:

TBA

November 28, 2001 Filed:

AMINE COMPOUNDS, RESIST COMPOSITIONS AND PATTERNING PROCESS For:

PRELIMINARY AMENDMENT

Assistant Commissioner for Patents Washington, D.C. 20231

Sir:

Prior to initial examination, please amend the above-identified application as follows:

IN THE CLAIMS:

Please amend the claims as follows:

(Amended) A process for forming a resist pattern comprising the steps 9.

of:

applying the resist composition of claim 5 onto a substrate to form a

coating,

heat treating the coating and then exposing it to high-energy radiation having a wavelength of less than 300 nm or electron beams through a photo mask, and optionally heat treating the exposed coating and developing it with a developer.